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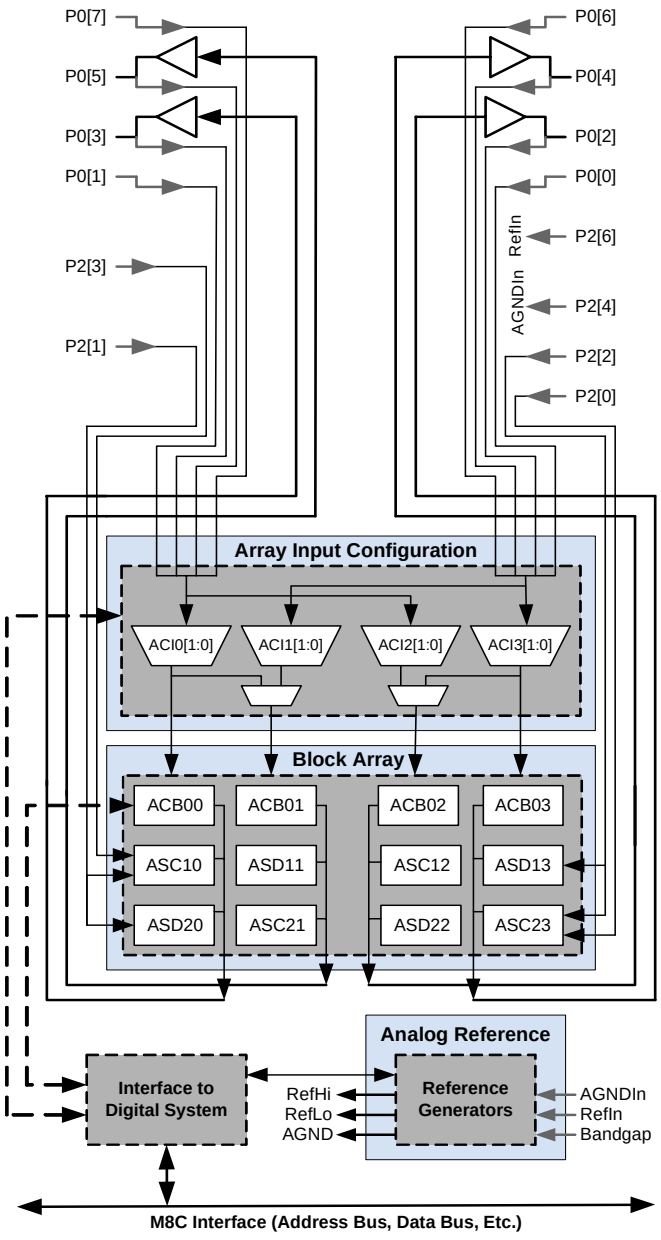
What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	M8C
Core Size	8-Bit
Speed	24MHz
Connectivity	I²C, SPI, UART/USART
Peripherals	POR, PWM, WDT
Number of I/O	16
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	256 x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.25V
Data Converters	A/D 4x14b; D/A 4x9b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	20-SSOP (0.209", 5.30mm Width)
Supplier Device Package	20-SSOP
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/cy8c27243-24pvi

Analog blocks are provided in columns of three, which includes one CT (Continuous Time) and two SC (Switched Capacitor) blocks, as shown in the figure below.



Analog System Block Diagram

Additional System Resources

System Resources, some of which have been previously listed, provide additional capability useful to complete systems. Additional resources include a multiplier, decimator, switch mode pump, low voltage detection, and power on reset. Brief statements describing the merits of each system resource are presented below.

- Digital clock dividers provide three customizable clock frequencies for use in applications. The clocks can be routed to both the digital and analog systems. Additional clocks can be generated using digital PSoC blocks as clock dividers.
- A multiply accumulate (MAC) provides a fast 8-bit multiplier with 32-bit accumulate, to assist in both general math as well as digital filters.
- The decimator provides a custom hardware filter for digital signal processing applications including the creation of Delta Sigma ADCs.
- The I2C module provides 100 and 400 kHz communication over two wires. Slave, master, and multi-master modes are all supported.
- Low Voltage Detection (LVD) interrupts can signal the application of falling voltage levels, while the advanced POR (Power On Reset) circuit eliminates the need for a system supervisor.
- An internal 1.3V reference provides an absolute reference for the analog system, including ADCs and DACs.
- An integrated switch mode pump (SMP) generates normal operating voltages from a single 1.2V battery cell, providing a low cost boost converter.

PSoC Device Characteristics

Depending on your PSoC device characteristics, the digital and analog systems can have 16, 8, or 4 digital blocks and 12, 6, or 3 analog blocks. The following table lists the resources available for specific PSoC device groups. The PSoC device covered by this data sheet is shown in the second row of the table.

PSoC Device Characteristics

PSoC Part Number	Digital IO	Digital Rows	Digital Blocks	Analog Inputs	Analog Outputs	Analog Columns	Analog Blocks
CY8C29x66	up to 64	4	16	12	4	4	12
CY8C27x43	**up to 44**	**2**	**8**	**12**	**4**	**4**	**12**
CY8C24x23	up to 24	1	4	12	2	2	6
CY8C24x23A	up to 24	1	4	12	2	2	6
CY8C22x13	up to 16	1	4	8	1	1	3

PSoC Designer Software Subsystems

Device Editor

The Device Editor subsystem allows the user to select different onboard analog and digital components called user modules using the PSoC blocks. Examples of user modules are ADCs, DACs, Amplifiers, and Filters.

The device editor also supports easy development of multiple configurations and dynamic reconfiguration. Dynamic configuration allows for changing configurations at run time.

PSoC Designer sets up power-on initialization tables for selected PSoC block configurations and creates source code for an application framework. The framework contains software to operate the selected components and, if the project uses more than one operating configuration, contains routines to switch between different sets of PSoC block configurations at run time. PSoC Designer can print out a configuration sheet for a given project configuration for use during application programming in conjunction with the Device Data Sheet. Once the framework is generated, the user can add application-specific code to flesh out the framework. It's also possible to change the selected components and regenerate the framework.

Design Browser

The Design Browser allows users to select and import preconfigured designs into the user's project. Users can easily browse a catalog of preconfigured designs to facilitate time-to-design. Examples provided in the tools include a 300-baud modem, LIN Bus master and slave, fan controller, and magnetic card reader.

Application Editor

In the Application Editor you can edit your C language and Assembly language source code. You can also assemble, compile, link, and build.

Assembler. The macro assembler allows the assembly code to be merged seamlessly with C code. The link libraries automatically use absolute addressing or can be compiled in relative mode, and linked with other software modules to get absolute addressing.

C Language Compiler. A C language compiler is available that supports Cypress MicroSystems' PSoC family devices. Even if you have never worked in the C language before, the product quickly allows you to create complete C programs for the PSoC family devices.

The embedded, optimizing C compiler provides all the features of C tailored to the PSoC architecture. It comes complete with embedded libraries providing port and bus operations, standard keypad and display support, and extended math functionality.

Debugger

The PSoC Designer Debugger subsystem provides hardware in-circuit emulation, allowing the designer to test the program in a physical system while providing an internal view of the PSoC device. Debugger commands allow the designer to read and program and read and write data memory, read and write IO registers, read and write CPU registers, set and clear breakpoints, and provide program run, halt, and step control. The debugger also allows the designer to create a trace buffer of registers and memory locations of interest.

Online Help System

The online help system displays online, context-sensitive help for the user. Designed for procedural and quick reference, each functional subsystem has its own context-sensitive help. This system also provides tutorials and links to FAQs and an Online Support Forum to aid the designer in getting started.

Hardware Tools

In-Circuit Emulator

A low cost, high functionality ICE (In-Circuit Emulator) is available for development support. This hardware has the capability to program single devices.

The emulator consists of a base unit that connects to the PC by way of the parallel or USB port. The base unit is universal and will operate with all PSoC devices. Emulation pods for each device family are available separately. The emulation pod takes the place of the PSoC device in the target board and performs full speed (24 MHz) operation.

1. Pin Information

This chapter describes, lists, and illustrates the CY8C27x43 PSoC device pins and pinout configurations.

1.1 Pinouts

The CY8C27x43 PSoC device is available in a variety of packages which are listed and illustrated in the following tables. Every port pin (labeled with a “P”) is capable of Digital IO. However, Vss, Vdd, SMP, and XRES are not capable of Digital IO.

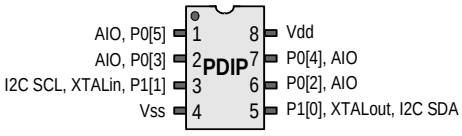
1.1.1 8-Pin Part Pinout

Table 1-1. 8-Pin Part Pinout (PDIP)

Pin No.	Type		Pin Name	Description
	Digital	Analog		
1	IO	IO	P0[5]	Analog column mux input and column output.
2	IO	IO	P0[3]	Analog column mux input and column output.
3	IO		P1[1]	Crystal Input (XTALin), I2C Serial Clock (SCL)
4	Power		Vss	Ground connection.
5	IO		P1[0]	Crystal Output (XTALout), I2C Serial Data (SDA)
6	IO	IO	P0[2]	Analog column mux input and column output.
7	IO	IO	P0[4]	Analog column mux input and column output.
8	Power		Vdd	Supply voltage.

LEGEND: A = Analog, I = Input, and O = Output.

CY8C27143 8-Pin PSoC Device



1.1.2 20-Pin Part Pinout

Table 1-2. 20-Pin Part Pinout (SSOP, SOIC)

Pin No.	Type		Pin Name	Description
	Digital	Analog		
1	IO	I	P0[7]	Analog column mux input.
2	IO	IO	P0[5]	Analog column mux input and column output.
3	IO	IO	P0[3]	Analog column mux input and column output.
4	IO	I	P0[1]	Analog column mux input.
5	Power		SMP	Switch Mode Pump (SMP) connection to external components required.
6	IO		P1[7]	I2C Serial Clock (SCL)
7	IO		P1[5]	I2C Serial Data (SDA)
8	IO		P1[3]	
9	IO		P1[1]	Crystal Input (XTALin), I2C Serial Clock (SCL)
10	Power		Vss	Ground connection.
11	IO		P1[0]	Crystal Output (XTALout), I2C Serial Data (SDA)
12	IO		P1[2]	
13	IO		P1[4]	Optional External Clock Input (EXTCLK)
14	IO		P1[6]	
15	Input		XRES	Active high external reset with internal pull down.
16	IO	I	P0[0]	Analog column mux input.
17	IO	IO	P0[2]	Analog column mux input and column output.
18	IO	IO	P0[4]	Analog column mux input and column output.
19	IO	I	P0[6]	Analog column mux input.
20	Power		Vdd	Supply voltage.

LEGEND: A = Analog, I = Input, and O = Output.

CY8C27243 20-Pin PSoC Device

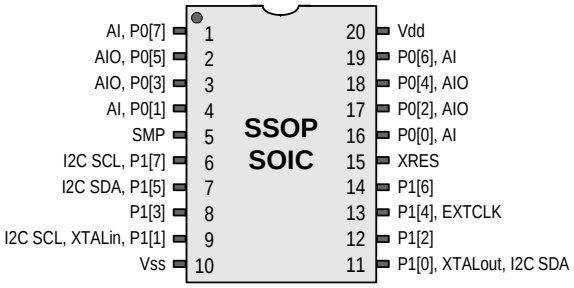
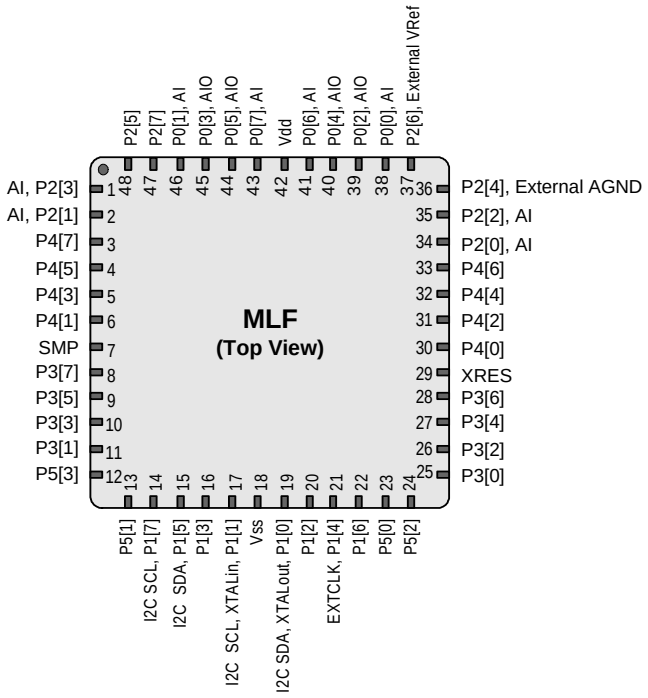


Table 1-6. 48-Pin Part Pinout (MLF*)

Pin No.	Type		Pin Name	Description
	Digital	Analog		
1	IO	I	P2[3]	Direct switched capacitor block input.
2	IO	I	P2[1]	Direct switched capacitor block input.
3	IO		P4[7]	
4	IO		P4[5]	
5	IO		P4[3]	
6	IO		P4[1]	
7	Power		SMP	Switch Mode Pump (SMP) connection to external components required.
8	IO		P3[7]	
9	IO		P3[5]	
10	IO		P3[3]	
11	IO		P3[1]	
12	IO		P5[3]	
13	IO		P5[1]	
14	IO		P1[7]	I2C Serial Clock (SCL)
15	IO		P1[5]	I2C Serial Data (SDA)
16	IO		P1[3]	
17	IO		P1[1]	Crystal Input (XTALin), I2C Serial Clock (SCL)
18	Power		Vss	Ground connection.
19	IO		P1[0]	Crystal Output (XTALout), I2C Serial Data (SDA)
20	IO		P1[2]	
21	IO		P1[4]	Optional External Clock Input (EXTCLK)
22	IO		P1[6]	
23	IO		P5[0]	
24	IO		P5[2]	
25	IO		P3[0]	
26	IO		P3[2]	
27	IO		P3[4]	
28	IO		P3[6]	
29	Input		XRES	Active high external reset with internal pull down.
30	IO		P4[0]	
31	IO		P4[2]	
32	IO		P4[4]	
33	IO		P4[6]	
34	IO	I	P2[0]	Direct switched capacitor block input.
35	IO	I	P2[2]	Direct switched capacitor block input.
36	IO		P2[4]	External Analog Ground (AGND)
37	IO		P2[6]	External Voltage Reference (VRef)
38	IO	I	P0[0]	Analog column mux input.
39	IO	IO	P0[2]	Analog column mux input and column output.
40	IO	IO	P0[4]	Analog column mux input and column output.
41	IO	I	P0[6]	Analog column mux input.
42	Power		Vdd	Supply voltage.
43	IO	I	P0[7]	Analog column mux input.
44	IO	IO	P0[5]	Analog column mux input and column output.
45	IO	IO	P0[3]	Analog column mux input and column output.
46	IO	I	P0[1]	Analog column mux input.
47	IO		P2[7]	
48	IO		P2[5]	

CY8C27643 48-Pin PSoC Device



LEGEND: A = Analog, I = Input, and O = Output.

* The MLF package has a center pad that must be connected to ground (Vss).

Register Map Bank 0 Table: User Space

Name	Addr (0,Hex)	Access	Name	Addr (0,Hex)	Access	Name	Addr (0,Hex)	Access	Name	Addr (0,Hex)	Access
PRT0DR	00	RW		40		ASC10CR0	80	RW		C0	
PRT0IE	01	RW		41		ASC10CR1	81	RW		C1	
PRT0GS	02	RW		42		ASC10CR2	82	RW		C2	
PRT0DM2	03	RW		43		ASC10CR3	83	RW		C3	
PRT1DR	04	RW		44		ASD11CR0	84	RW		C4	
PRT1IE	05	RW		45		ASD11CR1	85	RW		C5	
PRT1GS	06	RW		46		ASD11CR2	86	RW		C6	
PRT1DM2	07	RW		47		ASD11CR3	87	RW		C7	
PRT2DR	08	RW		48		ASC12CR0	88	RW		C8	
PRT2IE	09	RW		49		ASC12CR1	89	RW		C9	
PRT2GS	0A	RW		4A		ASC12CR2	8A	RW		CA	
PRT2DM2	0B	RW		4B		ASC12CR3	8B	RW		CB	
PRT3DR	0C	RW		4C		ASD13CR0	8C	RW		CC	
PRT3IE	0D	RW		4D		ASD13CR1	8D	RW		CD	
PRT3GS	0E	RW		4E		ASD13CR2	8E	RW		CE	
PRT3DM2	0F	RW		4F		ASD13CR3	8F	RW		CF	
PRT4DR	10	RW		50		ASD20CR0	90	RW		D0	
PRT4IE	11	RW		51		ASD20CR1	91	RW		D1	
PRT4GS	12	RW		52		ASD20CR2	92	RW		D2	
PRT4DM2	13	RW		53		ASD20CR3	93	RW		D3	
PRT5DR	14	RW		54		ASC21CR0	94	RW		D4	
PRT5IE	15	RW		55		ASC21CR1	95	RW		D5	
PRT5GS	16	RW		56		ASC21CR2	96	RW	I2C_CFG	D6	RW
PRT5DM2	17	RW		57		ASC21CR3	97	RW	I2C_SCR	D7	#
	18			58		ASD22CR0	98	RW	I2C_DR	D8	RW
	19			59		ASD22CR1	99	RW	I2C_MSCR	D9	#
	1A			5A		ASD22CR2	9A	RW	INT_CLR0	DA	RW
	1B			5B		ASD22CR3	9B	RW	INT_CLR1	DB	RW
	1C			5C		ASC23CR0	9C	RW		DC	
	1D			5D		ASC23CR1	9D	RW	INT_CLR3	DD	RW
	1E			5E		ASC23CR2	9E	RW	INT_MSK3	DE	RW
	1F			5F		ASC23CR3	9F	RW		DF	
DBB00DR0	20	#	AMX_IN	60	RW		A0		INT_MSK0	E0	RW
DBB00DR1	21	W		61			A1		INT_MSK1	E1	RW
DBB00DR2	22	RW		62			A2		INT_VC	E2	RC
DBB00CR0	23	#	ARF_CR	63	RW		A3		RES_WDT	E3	W
DBB01DR0	24	#	CMP_CR0	64	#		A4		DEC_DH	E4	RC
DBB01DR1	25	W	ASY_CR	65	#		A5		DEC_DL	E5	RC
DBB01DR2	26	RW	CMP_CR1	66	RW		A6		DEC_CR0	E6	RW
DBB01CR0	27	#		67			A7		DEC_CR1	E7	RW
DCB02DR0	28	#		68			A8		MUL_X	E8	W
DCB02DR1	29	W		69			A9		MUL_Y	E9	W
DCB02DR2	2A	RW		6A			AA		MUL_DH	EA	R
DCB02CR0	2B	#		6B			AB		MUL_DL	EB	R
DCB03DR0	2C	#		6C			AC		ACC_DR1	EC	RW
DCB03DR1	2D	W		6D			AD		ACC_DR0	ED	RW
DCB03DR2	2E	RW		6E			AE		ACC_DR3	EE	RW
DCB03CR0	2F	#		6F			AF		ACC_DR2	EF	RW
DBB10DR0	30	#	ACB00CR3	70	RW	RDI0RI	B0	RW		F0	
DBB10DR1	31	W	ACB00CR0	71	RW	RDI0SYN	B1	RW		F1	
DBB10DR2	32	RW	ACB00CR1	72	RW	RDI0IS	B2	RW		F2	
DBB10CR0	33	#	ACB00CR2	73	RW	RDI0LT0	B3	RW		F3	
DBB11DR0	34	#	ACB01CR3	74	RW	RDIOLT1	B4	RW		F4	
DBB11DR1	35	W	ACB01CR0	75	RW	RDI0RO0	B5	RW		F5	
DBB11DR2	36	RW	ACB01CR1	76	RW	RDI0RO1	B6	RW		F6	
DBB11CR0	37	#	ACB01CR2	77	RW		B7		CPU_F	F7	RL
DCB12DR0	38	#	ACB02CR3	78	RW	RDI1RI	B8	RW		F8	
DCB12DR1	39	W	ACB02CR0	79	RW	RDI1SYN	B9	RW		F9	
DCB12DR2	3A	RW	ACB02CR1	7A	RW	RDI1IS	BA	RW		FA	
DCB12CR0	3B	#	ACB02CR2	7B	RW	RDI1LT0	BB	RW		FB	
DCB13DR0	3C	#	ACB03CR3	7C	RW	RDI1LT1	BC	RW		FC	
DCB13DR1	3D	W	ACB03CR0	7D	RW	RDI1RO0	BD	RW		FD	
DCB13DR2	3E	RW	ACB03CR1	7E	RW	RDI1RO1	BE	RW	CPU_SCR1	FE	#
DCB13CR0	3F	#	ACB03CR2	7F	RW		BF		CPU_SCR0	FF	#

Blank fields are Reserved and should not be accessed. # Access is bit specific.

3. Electrical Specifications

This chapter presents the DC and AC electrical specifications of the CY8C27x43 PSoC device. For the most up to date electrical specifications, confirm that you have the most recent data sheet by going to the web at http://www.cypress.com/psoc.

Specifications are valid for -40°C ≤ T_A ≤ 85°C and T_J ≤ 100°C, except where noted. Specifications for devices running at greater than 12 MHz are valid for -40°C ≤ T_A ≤ 70°C and T_J ≤ 82°C.

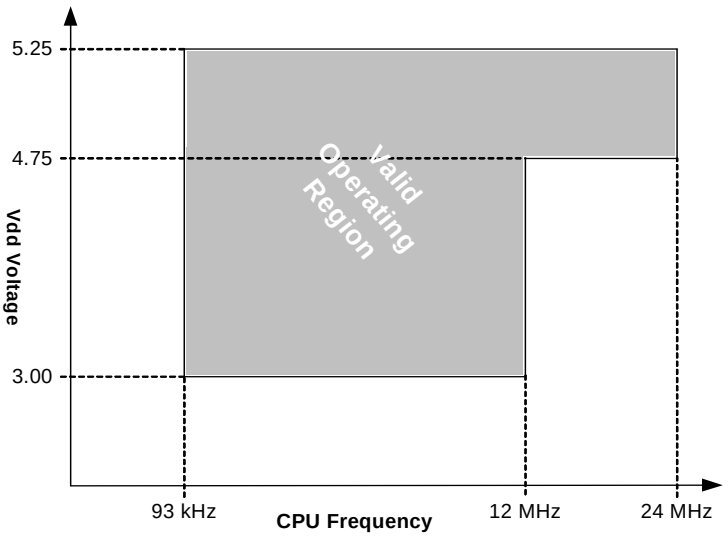


Figure 3-1. Voltage versus CPU Frequency

The following table lists the units of measure that are used in this chapter.

Table 3-1: Units of Measure

Symbol	Unit of Measure	Symbol	Unit of Measure
°C	degree Celsius	µW	micro watts
dB	decibels	mA	milli-ampere
fF	femto farad	ms	milli-second
Hz	hertz	mV	milli-volts
KB	1024 bytes	nA	nano ampere
Kbit	1024 bits	ns	nanosecond
kHz	kilohertz	nV	nanovolts
kΩ	kilohm	Ω	ohm
MHz	megahertz	pA	pico ampere
MΩ	megaohm	pF	pico farad
µA	micro ampere	pp	peak-to-peak
µF	micro farad	ppm	parts per million
µH	micro henry	ps	picosecond
µs	microsecond	sps	samples per second
µV	micro volts	σ	sigma: one standard deviation
µVrms	micro volts root-mean-square	V	volts

3.1 Absolute Maximum Ratings

Table 3-2. Absolute Maximum Ratings

Symbol	Description	Min	Typ	Max	Units	Notes
T_{STG}	Storage Temperature	-55	–	+100	°C	Higher storage temperatures will reduce data retention time.
T_A	Ambient Temperature with Power Applied	-40	–	+85	°C	
Vdd	Supply Voltage on Vdd Relative to Vss	-0.5	–	+6.0	V	
V_{IO}	DC Input Voltage	Vss- 0.5	–	Vdd + 0.5	V	
–	DC Voltage Applied to Tri-state	Vss - 0.5	–	Vdd + 0.5	V	
I_{MIO}	Maximum Current into any Port Pin	-25	–	+50	mA	
I_{MAIO}	Maximum Current into any Port Pin Configured as Analog Driver	-50	–	+50	mA	
ESD	Electro Static Discharge Voltage	2000	–	–	V	Human Body Model ESD
–	Latch-up Current	–	–	200	mA	

3.2 Operating Temperature

Table 3-3. Operating Temperature

Symbol	Description	Min	Typ	Max	Units	Notes
T_A	Ambient Temperature	-40	–	+85	°C	
T_J	Junction Temperature	-40	–	+100	°C	The temperature rise from ambient to junction is package specific. See “Thermal Impedances” on page 41. The user must limit the power consumption to comply with this requirement.

3.3 DC Electrical Characteristics

3.3.1 DC Chip-Level Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75V to 5.25V and -40°C ≤ T_A ≤ 85°C, or 3.0V to 3.6V and -40°C ≤ T_A ≤ 85°C, respectively. Typical parameters apply to 5V and 3.3V at 25°C and are for design guidance only.

Table 3-4. DC Chip-Level Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
Vdd	Supply Voltage	3.00	–	5.25	V	
I_{DD}	Supply Current	–	5	8	mA	Conditions are Vdd = 5.0V, T_A = 25 °C, CPU = 3 MHz, 48 MHz = Disabled. VC1 = 1.5 MHz, VC2 = 93.75 kHz, VC3 = 93.75 kHz.
I_{DD3}	Supply Current	–	3.3	6.0	mA	Conditions are Vdd = 3.3V, T_A = 25 °C, CPU = 3 MHz, 48 MHz = Disabled, VC1 = 1.5 MHz, VC2 = 93.75 kHz, VC3 = 93.75 kHz.
I_{SB}	Sleep (Mode) Current with POR, LVD, Sleep Timer, and WDT.[a]	–	3	6.5	µA	Conditions are with internal slow speed oscillator, Vdd = 3.3V, -40 °C ≤ T_A ≤ 55 °C.
I_{SBH}	Sleep (Mode) Current with POR, LVD, Sleep Timer, and WDT at high temperature.[a]	–	4	25	µA	Conditions are with internal slow speed oscillator, Vdd = 3.3V, 55 °C < T_A ≤ 85 °C.
I_{SBXTL}	Sleep (Mode) Current with POR, LVD, Sleep Timer, WDT, and external crystal.[a]	–	4	7.5	µA	Conditions are with properly loaded, 1 µW max, 32.768 kHz crystal. Vdd = 3.3V, -40 °C ≤ T_A ≤ 55 °C.
I_{SBXTLH}	Sleep (Mode) Current with POR, LVD, Sleep Timer, WDT, and external crystal at high temperature.[a]	–	5	26	µA	Conditions are with properly loaded, 1 µW max, 32.768 kHz crystal. Vdd = 3.3V, 55 °C < T_A ≤ 85 °C.
V_{REF}	Reference Voltage (Bandgap) for Silicon A [b]	1.275	1.300	1.325	V	Trimmed for appropriate Vdd.
V_{REF}	Reference Voltage (Bandgap) for Silicon B [b]	1.280	1.300	1.320	V	Trimmed for appropriate Vdd.

a. Standby current includes all functions (POR, LVD, WDT, Sleep Time) needed for reliable system operation. This should be compared with devices that have similar functions enabled.

b. Refer to the Ordering Information chapter on page 42.

3.3.2 DC General Purpose IO Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75V to 5.25V and -40°C ≤ T_A ≤ 85°C, or 3.0V to 3.6V and -40°C ≤ T_A ≤ 85°C, respectively. Typical parameters apply to 5V and 3.3V at 25°C and are for design guidance only.

Table 3-5. DC GPIO Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
R_{PU}	Pull up Resistor	4	5.6	8	kΩ	
R_{PD}	Pull down Resistor	4	5.6	8	kΩ	
V_{OH}	High Output Level	Vdd - 1.0	–	–	V	IOH = 10 mA, Vdd = 4.75 to 5.25V (8 total loads, 4 on even port pins (for example, P0[2], P1[4]), 4 on odd port pins (for example, P0[3], P1[5])).
V_{OL}	Low Output Level	–	–	0.75	V	IOL = 25 mA, Vdd = 4.75 to 5.25V (8 total loads, 4 on even port pins (for example, P0[2], P1[4]), 4 on odd port pins (for example, P0[3], P1[5])).
V_{IL}	Input Low Level	–	–	0.8	V	Vdd = 3.0 to 5.25
V_{IH}	Input High Level	2.1	–		V	Vdd = 3.0 to 5.25
V_H	Input Hysterisis	–	60	–	mV	
I_{IL}	Input Leakage (Absolute Value)	–	1	–	nA	Gross tested to 1 µA.
C_{IN}	Capacitive Load on Pins as Input	–	3.5	10	pF	Package and pin dependent. Temp = 25°C.
C_{OUT}	Capacitive Load on Pins as Output	–	3.5	10	pF	Package and pin dependent. Temp = 25°C.

3.3.3 DC Operational Amplifier Specifications

The following tables list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75V to 5.25V and -40°C ≤ T_A ≤ 85°C, or 3.0V to 3.6V and -40°C ≤ T_A ≤ 85°C, respectively. Typical parameters apply to 5V and 3.3V at 25°C and are for design guidance only.

The Operational Amplifier is a component of both the Analog Continuous Time PSoC blocks and the Analog Switched Cap PSoC blocks. The guaranteed specifications are measured in the Analog Continuous Time PSoC block. Typical parameters apply to 5V at 25°C and are for design guidance only.

Table 3-6. 5V DC Operational Amplifier Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
V_{OSOA}	Input Offset Voltage (absolute value)					
	Power = Low, Opamp Bias = High	–	1.6	10	mV	
	Power = Medium, Opamp Bias = High	–	1.3	8	mV	
	Power = High, Opamp Bias = High	–	1.2	7.5	mV	
TCV_{OSOA}	Average Input Offset Voltage Drift	–	7.0	35.0	µV/°C	
I_{EBOA}	Input Leakage Current (Port 0 Analog Pins)	–	20	–	pA	Gross tested to 1 µA.
C_{INOA}	Input Capacitance (Port 0 Analog Pins)	–	4.5	9.5	pF	Package and pin dependent. Temp = 25°C.
V_{CMOA}	Common Mode Voltage Range	0.0	–	Vdd	V	The common-mode input voltage range is measured through an analog output buffer. The specification includes the limitations imposed by the characteristics of the analog output buffer.
	Common Mode Voltage Range (high power or high opamp bias)	0.5	–	Vdd - 0.5		
$CMRR_{OA}$	Common Mode Rejection Ratio		–	–	dB	Specification is applicable at high power. For all other bias modes (except high power, high opamp bias), minimum is 60 dB.
	Power = Low	60				
	Power = Medium	60				
	Power = High	60				
G_{OLOA}	Open Loop Gain		–	–	dB	Specification is applicable at high power. For all other bias modes (except high power, high opamp bias), minimum is 60 dB.
	Power = Low	60				
	Power = Medium	60				
	Power = High	80				
$V_{OHIGHOA}$	High Output Voltage Swing (internal signals)					
	Power = Low	Vdd - 0.2	–	–	V	
	Power = Medium	Vdd - 0.2	–	–	V	
	Power = High	Vdd - 0.5	–	–	V	
V_{OLOWOA}	Low Output Voltage Swing (internal signals)					
	Power = Low	–	–	0.2	V	
	Power = Medium	–	–	0.2	V	
	Power = High	–	–	0.5	V	
I_{SOA}	Supply Current (including associated AGND buffer)					
	Power = Low, Opamp Bias = Low	–	150	200	µA	
	Power = Low, Opamp Bias = High	–	300	400	µA	
	Power = Medium, Opamp Bias = Low	–	600	800	µA	
	Power = Medium, Opamp Bias = High	–	1200	1600	µA	
	Power = High, Opamp Bias = Low	–	2400	3200	µA	
	Power = High, Opamp Bias = High	–	4600	6400	µA	
$PSRR_{OA}$	Supply Voltage Rejection Ratio	60	–	–	dB	0V ≤ V_{IN} ≤ (Vdd - 2.25) or (Vdd - 1.25V) ≤ V_{IN} ≤ Vdd.

Table 3-7. 3.3V DC Operational Amplifier Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
V_{OSOA}	Input Offset Voltage (absolute value)					
	Power = Low, Opamp Bias = High	–	1.65	10	mV	
	Power = Medium, Opamp Bias = High	–	1.32	8	mV	
	High Power is 5 Volts Only					
TCV_{OSOA}	Average Input Offset Voltage Drift	–	7.0	35.0	µV/°C	
I_{EBOA}	Input Leakage Current (Port 0 Analog Pins)	–	20	–	pA	Gross tested to 1 µA.
C_{INOA}	Input Capacitance (Port 0 Analog Pins)	–	4.5	9.5	pF	Package and pin dependent. Temp = 25°C.
V_{CMOA}	Common Mode Voltage Range	0.2	–	Vdd - 0.2	V	The common-mode input voltage range is measured through an analog output buffer. The specification includes the limitations imposed by the characteristics of the analog output buffer.
$CMRR_{OA}$	Common Mode Rejection Ratio		–	–	dB	Specification is applicable at high power. For all other bias modes (except high power, high opamp bias), minimum is 60 dB.
	Power = Low	50				
	Power = Medium	50				
	Power = High	50				
G_{OLOA}	Open Loop Gain		–	–	dB	Specification is applicable at high power. For all other bias modes (except high power, high opamp bias), minimum is 60 dB.
	Power = Low	60				
	Power = Medium	60				
	Power = High	80				
$V_{OHIGHOA}$	High Output Voltage Swing (internal signals)					
	Power = Low	Vdd - 0.2	–	–	V	
	Power = Medium	Vdd - 0.2	–	–	V	
	Power = High is 5V only	Vdd - 0.2	–	–	V	
V_{OLOWOA}	Low Output Voltage Swing (internal signals)					
	Power = Low	–	–	0.2	V	
	Power = Medium	–	–	0.2	V	
	Power = High	–	–	0.2	V	
I_{SOA}	Supply Current (including associated AGND buffer)					
	Power = Low, Opamp Bias = Low	–	150	200	µA	
	Power = Low, Opamp Bias = High	–	300	400	µA	
	Power = Medium, Opamp Bias = Low	–	600	800	µA	
	Power = Medium, Opamp Bias = High	–	1200	1600	µA	
	Power = High, Opamp Bias = Low	–	2400	3200	µA	
	Power = High, Opamp Bias = High	–	4600	6400	µA	
$PSRR_{OA}$	Supply Voltage Rejection Ratio	50	–	–	dB	$0V \le V_{IN} \le (Vdd - 2.25)$ or $(Vdd - 1.25V) \le V_{IN} \le Vdd$.

3.3.5 DC Switch Mode Pump Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75V to 5.25V and -40°C ≤ T_A ≤ 85°C, or 3.0V to 3.6V and -40°C ≤ T_A ≤ 85°C, respectively. Typical parameters apply to 5V and 3.3V at 25°C and are for design guidance only.

Table 3-10. DC Switch Mode Pump (SMP) Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
V_{PUMP} 5V	5V Output Voltage	4.75	5.0	5.25	V	Configuration of footnote [a]. Average, neglecting ripple. SMP trip voltage is set to 5.0V.
V_{PUMP} 3V	3V Output Voltage	3.00	3.25	3.60	V	Configuration of footnote [a]. Average, neglecting ripple. SMP trip voltage is set to 3.25V.
I_{PUMP}	Available Output Current V_{BAT} = 1.5V, V_{PUMP} = 3.25V V_{BAT} = 1.8V, V_{PUMP} = 5.0V	 8 5	 – –	 – –	 mA mA	Configuration of footnote [a]. SMP trip voltage is set to 3.25V. SMP trip voltage is set to 5.0V.
V_{BAT}5V	Input Voltage Range from Battery	1.8	–	5.0	V	Configuration of footnote [a]. SMP trip voltage is set to 5.0V.
V_{BAT}3V	Input Voltage Range from Battery	1.0	–	3.3	V	Configuration of footnote [a]. SMP trip voltage is set to 3.25V.
$V_{BATSTART}$	Minimum Input Voltage from Battery to Start Pump	1.1	–	–	V	Configuration of footnote [a].
ΔV_{PUMP_Line}	Line Regulation (over V_{BAT} range)	–	5	–	$\%V_O$	Configuration of footnote [a]. V_O is the "Vdd Value for PUMP Trip" specified by the VM[2:0] setting in the DC POR and LVD Specification, Table 3-16 on page 26.
ΔV_{PUMP_Load}	Load Regulation	–	5	–	$\%V_O$	Configuration of footnote [a]. V_O is the "Vdd Value for PUMP Trip" specified by the VM[2:0] setting in the DC POR and LVD Specification, Table 3-16 on page 26.
ΔV_{PUMP_Ripple}	Output Voltage Ripple (depends on capacitor/load)	–	100	–	mVpp	Configuration of footnote [a]. Load is 5mA.
E_3	Efficiency	35	50	–	%	Configuration of footnote [a]. Load is 5 mA. SMP trip voltage is set to 3.25V.
F_{PUMP}	Switching Frequency	–	1.3	–	MHz	
DC_{PUMP}	Switching Duty Cycle	–	50	–	%	

a. L_1 = 2 µH inductor, C_1 = 10 µF capacitor, D_1 = Schottky diode. See Figure 3-2.

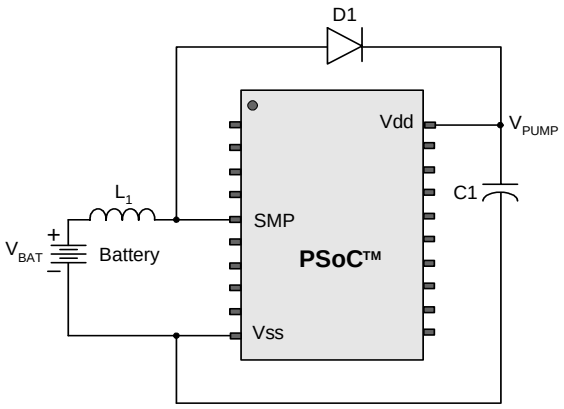


Figure 3-2. Basic Switch Mode Pump Circuit

3.4 AC Electrical Characteristics

3.4.1 AC Chip-Level Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75V to 5.25V and -40°C ≤ T_A ≤ 85°C, or 3.0V to 3.6V and -40°C ≤ T_A ≤ 85°C, respectively. Typical parameters apply to 5V and 3.3V at 25°C and are for design guidance only.

Table 3-18. AC Chip-Level Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
F_{IMO}	Internal Main Oscillator Frequency	23.4	24	24.6[a]	MHz	Trimmed. Utilizing factory trim values.
F_{CPU1}	CPU Frequency (5V Nominal)	0.93	24	24.6[a,b]	MHz	Trimmed. Utilizing factory trim values.
F_{CPU2}	CPU Frequency (3.3V Nominal)	0.93	12	12.3[b,c]	MHz	Trimmed. Utilizing factory trim values.
F_{48M}	Digital PSoC Block Frequency	0	48	49.2[a,b,d]	MHz	Refer to the AC Digital Block Specifications below.
F_{24M}	Digital PSoC Block Frequency	0	24	24.6[b, d]	MHz	
F_{32K1}	Internal Low Speed Oscillator Frequency	15	32	64	kHz	
F_{32K2}	External Crystal Oscillator	–	32.768	–	kHz	Accuracy is capacitor and crystal dependent. 50% duty cycle.
F_{PLL}	PLL Frequency	–	23.986	–	MHz	Multiple (x732) of crystal frequency.
Jitter24M2	24 MHz Period Jitter (PLL)	–	–	600	ps	
$T_{PLLSLEW}$	PLL Lock Time	0.5	–	10	ms	
$T_{PLLSLEWS-LOW}$	PLL Lock Time for Low Gain Setting	0.5	–	50	ms	
T_{OS}	External Crystal Oscillator Startup to 1%	–	1700	2620	ms	
T_{OSACC}	External Crystal Oscillator Startup to 100 ppm	–	2800	3800	ms	The crystal oscillator frequency is within 100 ppm of its final value by the end of the T_{osacc} period. Correct operation assumes a properly loaded 1 uW maximum drive level 32.768 kHz crystal. 3.0V ≤ Vdd ≤ 5.5V, -40 ^{0}C ≤ T_A ≤ 85 ^{0}C.
Jitter32k	32 kHz Period Jitter	–	100		ns	
T_{XRST}	External Reset Pulse Width	10	–	–	µs	
DC24M	24 MHz Duty Cycle	40	50	60	%	
Step24M	24 MHz Trim Step Size	–	50	–	kHz	
Fout48M	48 MHz Output Frequency	46.8	48.0	49.2[a,c]	MHz	Trimmed. Utilizing factory trim values.
Jitter24M1	24 MHz Period Jitter (IMO)	–	600		ps	
F_{MAX}	Maximum frequency of signal on row input or row output.	–	–	12.3	MHz	
T_{RAMP}	Supply Ramp Time	0	–	–	µs	

a. 4.75V < Vdd < 5.25V.
b. Accuracy derived from Internal Main Oscillator with appropriate trim for Vdd range.
c. 3.0V < Vdd < 3.6V. See Application Note AN2012 “Adjusting PSoC Microcontroller Trims for Dual Voltage-Range Operation” for information on trimming for operation at 3.3V.
d. See the individual user module data sheets for information on maximum frequencies for user modules.

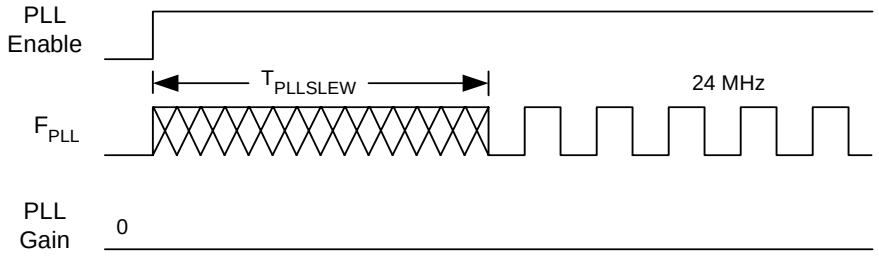


Figure 3-3. PLL Lock Timing Diagram

3.4.3 AC Operational Amplifier Specifications

The following tables list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75V to 5.25V and -40°C ≤ T_A ≤ 85°C, or 3.0V to 3.6V and -40°C ≤ T_A ≤ 85°C, respectively. Typical parameters apply to 5V and 3.3V at 25°C and are for design guidance only.

Settling times, slew rates, and gain bandwidth are based on the Analog Continuous Time PSoC block.

Power = High and Opamp Bias = High is not supported at 3.3V.

Table 3-20. 5V AC Operational Amplifier Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
T_{ROA}	Rising Settling Time from 80% of ΔV to 0.1% of ΔV (10 pF load, Unity Gain)					
	Power = Low, Opamp Bias = Low	–	–	3.9	µs	
	Power = Medium, Opamp Bias = High	–	–	0.72	µs	
	Power = High, Opamp Bias = High	–	–	0.62	µs	
T_{SOA}	Falling Settling Time from 20% of ΔV to 0.1% of ΔV (10 pF load, Unity Gain)					
	Power = Low, Opamp Bias = Low	–	–	5.9	µs	
	Power = Medium, Opamp Bias = High	–	–	0.92	µs	
	Power = High, Opamp Bias = High	–	–	0.72	µs	
SR_{ROA}	Rising Slew Rate (20% to 80%)(10 pF load, Unity Gain)					
	Power = Low, Opamp Bias = Low	0.15	–	–	V/µs	
	Power = Medium, Opamp Bias = High	1.7	–	–	V/µs	
	Power = High, Opamp Bias = High	6.5	–	–	V/µs	
SR_{FOA}	Falling Slew Rate (20% to 80%)(10 pF load, Unity Gain)					
	Power = Low, Opamp Bias = Low	0.01	–	–	V/µs	
	Power = Medium, Opamp Bias = High	0.5	–	–	V/µs	
	Power = High, Opamp Bias = High	4.0	–	–	V/µs	
BW_{OA}	Gain Bandwidth Product					
	Power = Low, Opamp Bias = Low	0.75	–	–	MHz	
	Power = Medium, Opamp Bias = High	3.1	–	–	MHz	
	Power = High, Opamp Bias = High	5.4	–	–	MHz	
E_{NOA}	Noise at 1 kHz (Power = Medium, Opamp Bias = High)	–	100	–	nV/rt-Hz	

Table 3-21. 3.3V AC Operational Amplifier Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
T_{ROA}	Rising Settling Time from 80% of ΔV to 0.1% of ΔV (10 pF load, Unity Gain)					
	Power = Low, Opamp Bias = Low	–	–	3.92	µs	
	Power = Low, Opamp Bias = High	–	–	0.72	µs	
T_{SOA}	Falling Settling Time from 20% of ΔV to 0.1% of ΔV (10 pF load, Unity Gain)					
	Power = Low, Opamp Bias = Low	–	–	5.41	µs	
	Power = Medium, Opamp Bias = High	–	–	0.72	µs	
SR_{ROA}	Rising Slew Rate (20% to 80%)(10 pF load, Unity Gain)					
	Power = Low, Opamp Bias = Low	0.31	–	–	V/µs	
	Power = Medium, Opamp Bias = High	2.7	–	–	V/µs	
SR_{FOA}	Falling Slew Rate (20% to 80%)(10 pF load, Unity Gain)					
	Power = Low, Opamp Bias = Low	0.24	–	–	V/µs	
	Power = Medium, Opamp Bias = High	1.8	–	–	V/µs	
BW_{OA}	Gain Bandwidth Product					
	Power = Low, Opamp Bias = Low	0.67	–	–	MHz	
	Power = Medium, Opamp Bias = High	2.8	–	–	MHz	
E_{NOA}	Noise at 1 kHz (Power = Medium, Opamp Bias = High)	–	100	–	nV/rt-Hz	

3.4.5 AC Analog Output Buffer Specifications

The following tables list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75V to 5.25V and -40°C ≤ T_A ≤ 85°C, or 3.0V to 3.6V and -40°C ≤ T_A ≤ 85°C, respectively. Typical parameters apply to 5V and 3.3V at 25°C and are for design guidance only.

Table 3-23. 5V AC Analog Output Buffer Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
T_{ROB}	Rising Settling Time to 0.1%, 1V Step, 100pF Load					
	Power = Low	–	–	2.5	µs	
	Power = High	–	–	2.5	µs	
T_{SOB}	Falling Settling Time to 0.1%, 1V Step, 100pF Load					
	Power = Low	–	–	2.2	µs	
	Power = High	–	–	2.2	µs	
SR_{ROB}	Rising Slew Rate (20% to 80%), 1V Step, 100pF Load					
	Power = Low	0.65	–	–	V/µs	
	Power = High	0.65	–	–	V/µs	
SR_{FOB}	Falling Slew Rate (80% to 20%), 1V Step, 100pF Load					
	Power = Low	0.65	–	–	V/µs	
	Power = High	0.65	–	–	V/µs	
BW_{OB}	Small Signal Bandwidth, 20mV_{pp}, 3dB BW, 100pF Load					
	Power = Low	0.8	–	–	MHz	
	Power = High	0.8	–	–	MHz	
BW_{OB}	Large Signal Bandwidth, 1V_{pp}, 3dB BW, 100pF Load					
	Power = Low	300	–	–	kHz	
	Power = High	300	–	–	kHz	

Table 3-24. 3.3V AC Analog Output Buffer Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
T_{ROB}	Rising Settling Time to 0.1%, 1V Step, 100pF Load					
	Power = Low	–	–	3.8	µs	
	Power = High	–	–	3.8	µs	
T_{SOB}	Falling Settling Time to 0.1%, 1V Step, 100pF Load					
	Power = Low	–	–	2.6	µs	
	Power = High	–	–	2.6	µs	
SR_{ROB}	Rising Slew Rate (20% to 80%), 1V Step, 100pF Load					
	Power = Low	0.5	–	–	V/µs	
	Power = High	0.5	–	–	V/µs	
SR_{FOB}	Falling Slew Rate (80% to 20%), 1V Step, 100pF Load					
	Power = Low	0.5	–	–	V/µs	
	Power = High	0.5	–	–	V/µs	
BW_{OB}	Small Signal Bandwidth, 20mV_{pp}, 3dB BW, 100pF Load					
	Power = Low	0.7	–	–	MHz	
	Power = High	0.7	–	–	MHz	
BW_{OB}	Large Signal Bandwidth, 1V_{pp}, 3dB BW, 100pF Load					
	Power = Low	200	–	–	kHz	
	Power = High	200	–	–	kHz	

3.4.6 AC External Clock Specifications

The following tables list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75V to 5.25V and -40°C ≤ T_A ≤ 85°C, or 3.0V to 3.6V and -40°C ≤ T_A ≤ 85°C, respectively. Typical parameters apply to 5V and 3.3V at 25°C and are for design guidance only.

Table 3-25. 5V AC External Clock Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
F_{OSCEXT}	Frequency	0.093	–	24.6	MHz	
–	High Period	20.6	–	5300	ns	
–	Low Period	20.6	–	–	ns	
–	Power Up IMO to Switch	150	–	–	µs	

Table 3-26. 3.3V AC External Clock Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
F_{OSCEXT}	Frequency with CPU Clock divide by 1[a]	0.093	–	12.3	MHz	
F_{OSCEXT}	Frequency with CPU Clock divide by 2 or greater[b]	0.186	–	24.6	MHz	
–	High Period with CPU Clock divide by 1	41.7	–	5300	ns	
–	Low Period with CPU Clock divide by 1	41.7	–	–	ns	
–	Power Up IMO to Switch	150	–	–	µs	

a. Maximum CPU frequency is 12 MHz at 3.3V. With the CPU clock divider set to 1, the external clock must adhere to the maximum frequency and duty cycle requirements.
b. If the frequency of the external clock is greater than 12 MHz, the CPU clock divider must be set to 2 or greater. In this case, the CPU clock divider will ensure that the fifty percent duty cycle requirement is met.

3.4.7 AC Programming Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75V to 5.25V and -40°C ≤ T_A ≤ 85°C, or 3.0V to 3.6V and -40°C ≤ T_A ≤ 85°C, respectively. Typical parameters apply to 5V and 3.3V at 25°C and are for design guidance only.

Table 3-27. AC Programming Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
T_{RSCLK}	Rise Time of SCLK	1	–	20	ns	
T_{FSCLK}	Fall Time of SCLK	1	–	20	ns	
T_{SSCLK}	Data Set up Time to Falling Edge of SCLK	40	–	–	ns	
T_{HSCLK}	Data Hold Time from Falling Edge of SCLK	40	–	–	ns	
F_{SCLK}	Frequency of SCLK	0	–	8	MHz	
T_{ERASEB}	Flash Erase Time (Block)	–	10	–	ms	
T_{WRITE}	Flash Block Write Time	–	10	–	ms	
T_{DSCLK}	Data Out Delay from Falling Edge of SCLK	–	–	45	ns	Vdd > 3.6
T_{DSCLK3}	Data Out Delay from Falling Edge of SCLK	–	–	50	ns	3.0 ≤ Vdd ≤ 3.6

4. Packaging Information

This chapter illustrates the packaging specifications for the CY8C27x43 PSoC device, along with the thermal impedances for each package and the typical package capacitance on crystal pins.

Important Note Emulation tools may require a larger area on the target PCB than the chip's footprint. For a detailed description of the emulation tools' dimensions, refer to the document titled *PSoC Emulator Pod Dimensions* at http://www.cypress.com/support/link.cfm?mr=poddim.

4.1 Packaging Dimensions

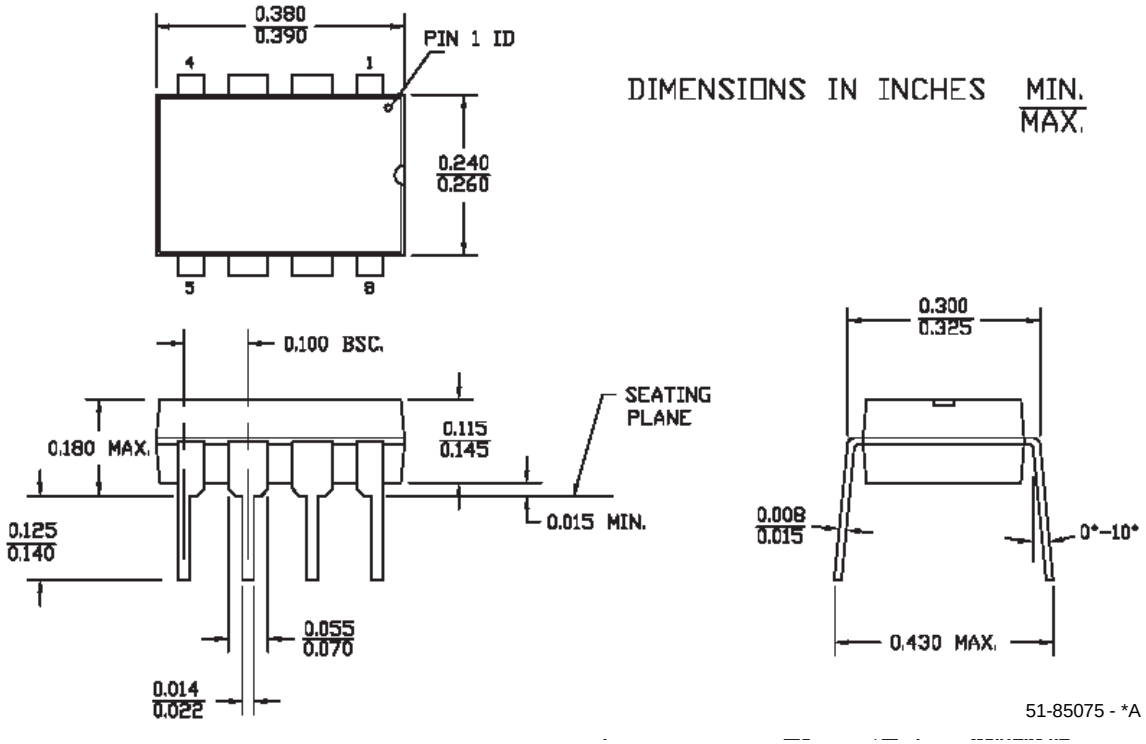


Figure 4-1. 8-Lead (300-Mil) PDIP

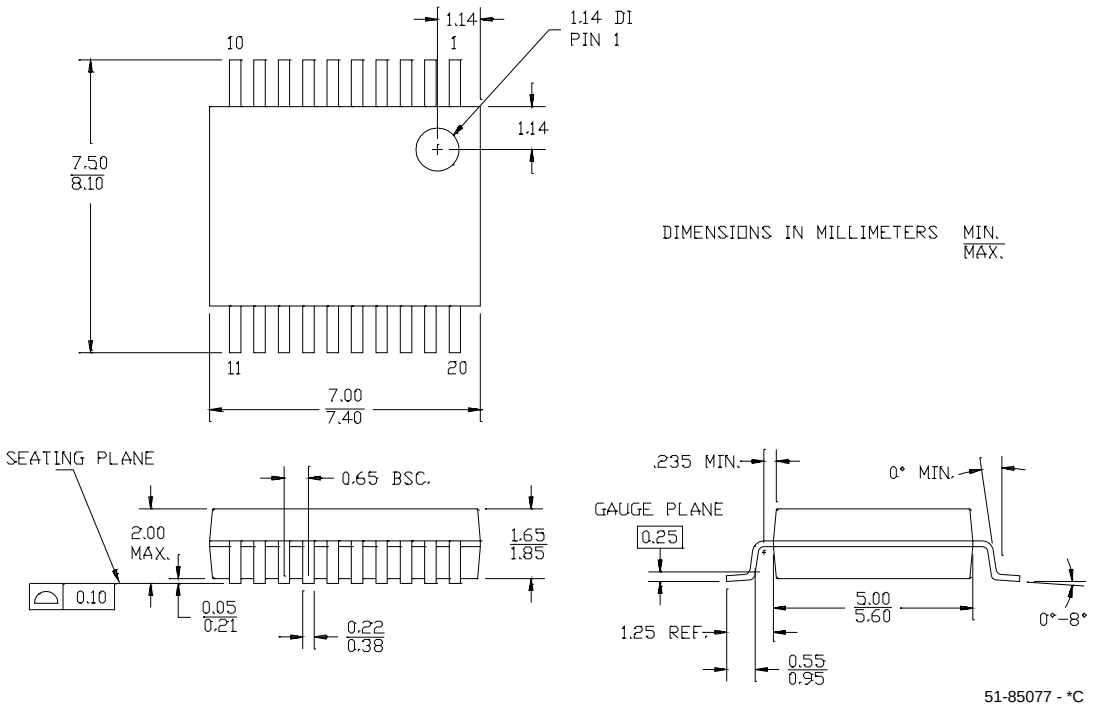


Figure 4-2. 20-Lead (210-Mil) SSOP

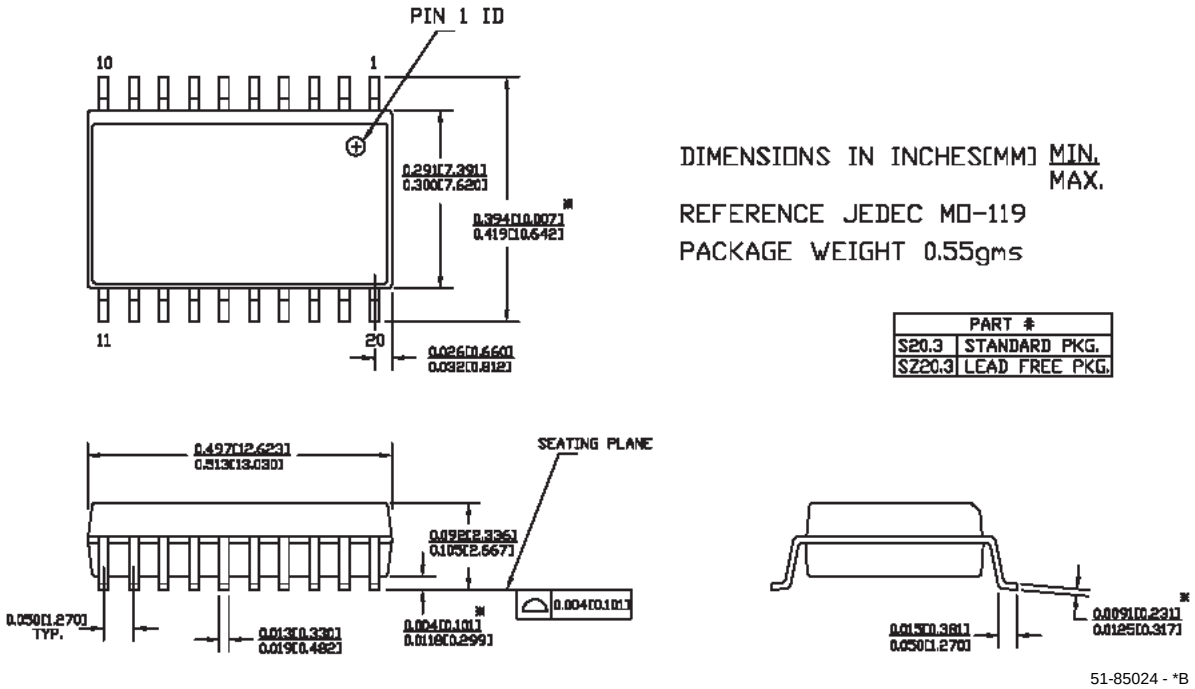


Figure 4-3. 20-Lead (300-Mil) Molded SOIC

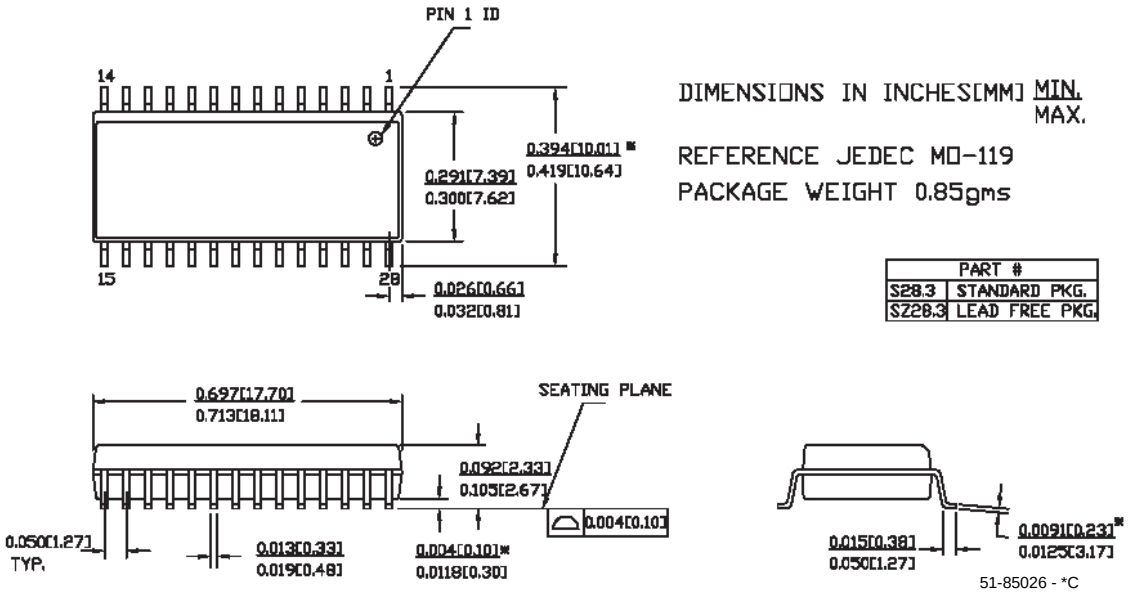


Figure 4-6. 28-Lead (300-Mil) Molded SOIC

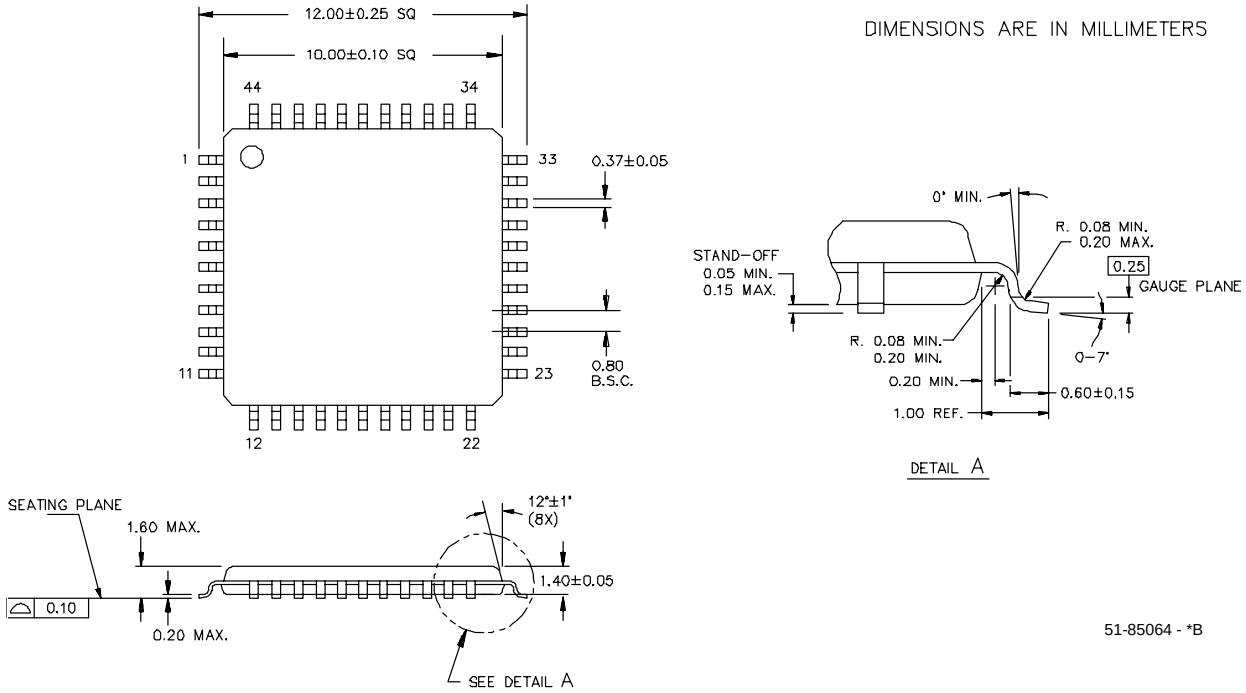


Figure 4-7. 44-Lead TQFP

5. Ordering Information

The following table lists the CY8C27x43 PSoC device family's key package features and ordering codes.

Table 5-1. CY8C27x43 PSoC Device Family Key Features and Ordering Information

Package	Ordering Code	Flash (Kbytes)	RAM (Bytes)	Switch Mode Pump	Temperature Range	Digital Blocks (Rows of 4)	Analog Blocks (Columns of 3)	Digital IO Pins	Analog Inputs	Analog Outputs	XRES Pin
CY8C27x43 Silicon B – These parts are lead free and offer the following improvements. The DEC_CR1 register selections are enhanced to allow any digital block to be the decimator clock source, the ECO EX and ECO EXW bits in the CPU_SCR1 register are readable, and the accuracy of the analog reference is enhanced (see the Electrical Specifications chapter). All silicon A errata are fixed in silicon B.											
8 Pin (300 Mil) DIP	CY8C27143-24PXI	16	256	No	-40C to +85C	8	12	6	4	4	No
20 Pin (210 Mil) SSOP	CY8C27243-24PVXI	16	256	Yes	-40C to +85C	8	12	16	8	4	Yes
20 Pin (210 Mil) SSOP (Tape and Reel)	CY8C27243-24PVXIT	16	256	Yes	-40C to +85C	8	12	16	8	4	Yes
20 Pin (300 Mil) SOIC	CY8C27243-24SXI	16	256	Yes	-40C to +85C	8	12	16	8	4	Yes
20 Pin 300 Mil) SOIC (Tape and Reel)	CY8C27243-24SXIT	16	256	Yes	-40C to +85C	8	12	16	8	4	Yes
28 Pin (300 Mil) DIP	CY8C27443-24PXI	16	256	Yes	-40C to +85C	8	12	24	12	4	Yes
28 Pin (210 Mil) SSOP	CY8C27443-24PVXI	16	256	Yes	-40C to +85C	8	12	24	12	4	Yes
28 Pin (210 Mil) SSOP (Tape and Reel)	CY8C27443-24PVXIT	16	256	Yes	-40C to +85C	8	12	24	12	4	Yes
28 Pin (300 Mil) SOIC	CY8C27443-24SXI	16	256	Yes	-40C to +85C	8	12	24	12	4	Yes
28 Pin (300 Mil) SOIC (Tape and Reel)	CY8C27443-24SXIT	16	256	Yes	-40C to +85C	8	12	24	12	4	Yes
44 Pin TQFP	CY8C27543-24AXI	16	256	Yes	-40C to +85C	8	12	40	12	4	Yes
44 Pin TQFP (Tape and Reel)	CY8C27543-24AXIT	16	256	Yes	-40C to +85C	8	12	40	12	4	Yes
48 Pin (300 Mil) SSOP	CY8C27643-24PVXI	16	256	Yes	-40C to +85C	8	12	44	12	4	Yes
48 Pin (300 Mil) SSOP (Tape and Reel)	CY8C27643-24PVXIT	16	256	Yes	-40C to +85C	8	12	44	12	4	Yes
48 Pin (7x7) MLF	CY8C27643-24LFXI	16	256	Yes	-40C to +85C	8	12	44	12	4	Yes
48 Pin (7x7) MLF (Tape and Reel)	CY8C27643-24LFXIT	16	256	Yes	-40C to +85C	8	12	44	12	4	Yes
CY8C27x43 Silicon A – Silicon A is not recommended for new designs.											
8 Pin (300 Mil) DIP	CY8C27143-24PI	16	256	No	-40C to +85C	8	12	6	4	4	No
20 Pin (210 Mil) SSOP	CY8C27243-24PVI	16	256	Yes	-40C to +85C	8	12	16	8	4	Yes
20 Pin (210 Mil) SSOP (Tape and Reel)	CY8C27243-24PVIT	16	256	Yes	-40C to +85C	8	12	16	8	4	Yes
20 Pin (300 Mil) SOIC	CY8C27243-24SI	16	256	Yes	-40C to +85C	8	12	16	8	4	Yes
20 Pin 300 Mil) SOIC (Tape and Reel)	CY8C27243-24SIT	16	256	Yes	-40C to +85C	8	12	16	8	4	Yes
28 Pin (300 Mil) DIP	CY8C27443-24PI	16	256	Yes	-40C to +85C	8	12	24	12	4	Yes
28 Pin (210 Mil) SSOP	CY8C27443-24PVI	16	256	Yes	-40C to +85C	8	12	24	12	4	Yes